

#### DESCRIPTION

The SPN4906 is the Dual N-Channel enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology. This high density process is especially tailored to minimize on-state resistance and provide superior switching performance. These devices are particularly suited for low voltage applications such as notebook computer power management and other battery powered circuits where high-side switching, low in-line power loss, and resistance to transients are needed.

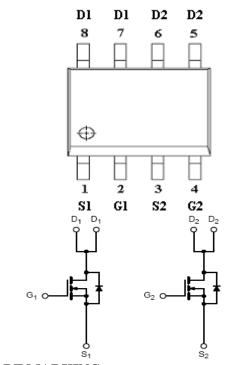
#### **FEATURES**

- N-Channel
   40V/6.0A,RDS(ON)=45mΩ@VGS=10V
   40V/5.0A,RDS(ON)=54mΩ@VGS=4.5V
   40V/4.5A,RDS(ON)=83mΩ@VGS=2.5V
- ◆ Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ♦ SOP–8 package design

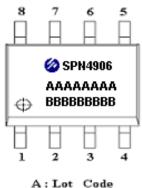
#### **APPLICATIONS**

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

### PIN CONFIGURATION(SOP-8)



# **PART MARKING**



A : Lot Code B : Date Code

PIN DESCRIPTION						
Pin	Symbol	Description				
1	S1	Source 1				
2	G1	Gate 1				
3	S2	Source 2				
4	G2	Gate 2				
5	D2	Drain 2				
6	D2	Drain 2				
7	D1	Drain 1				
8	D1	Drain 1				

# **ORDERING INFORMATION**

Part Number	Package	Part Marking
SPN4906S8RGB	SOP-8	SPN4906

<sup>※</sup> SPN4906S8RGB 13" Tape Reel; Pb − Free; Halogen − Free

## **ABSOULTE MAXIMUM RATINGS**

(TA=25°C Unless otherwise noted)

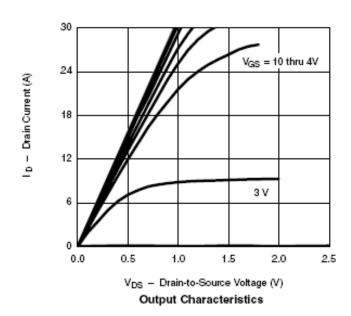
Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		Vdss	40	V	
Gate –Source Voltage		VGSS	±20	V	
Continuous Drain Current(T <sub>J</sub> =150°C)	Ta=25°C	- Id	6.0	A	
	Ta=70°C		5.0		
Pulsed Drain Current		IDM	25	Α	
Continuous Source Current(Diode Conduction)		Is	2.3	A	
Power Dissipation	Ta=25°C	PD	2.5	W	
	Ta=70°C		1.6	W	
Operating Junction Temperature		Тл	-55/150	°C	
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient	$T \le 10 sec$ Steady State	RθJA	50 80	°C/W	

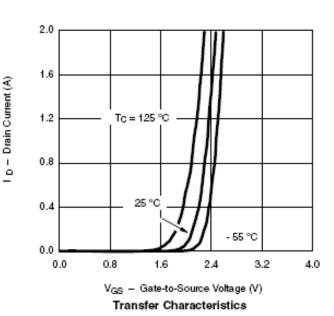
# **ELECTRICAL CHARACTERISTICS**

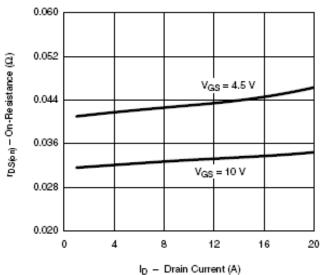
(TA=25°C Unless otherwise noted)

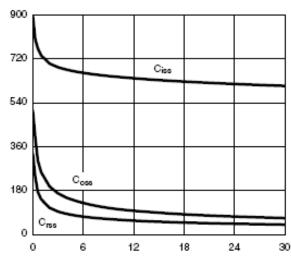
Parameter	Symbol	Symbol Conditions		Тур	Max.	Unit
Static	·					<u>, I                                   </u>
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	40			V
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	0.5		1.0	]
Gate Leakage Current	Igss	VDS=0V,VGS=±12V			±100	nA
		VDS=40V,VGS=0V	1		1	
Zero Gate Voltage Drain Current	Idss	V <sub>DS</sub> =40V,V <sub>GS</sub> =0V T <sub>J</sub> =85°C			5	uA
On-State Drain Current	ID(on)	$V_{DS} = 5V, V_{GS} = 4.5V$	10			A
	RDS(on)	Vgs= 10V,Id=6.0A		0.040	0.045	Ω
Drain-Source On-Resistance		VGS=4.5V,ID=5.0A VGS=2.5V,ID=4.5A		0.047	0.054	
Forward Transconductance	gfs	VDS=15V,ID=6.2A		13		S
Diode Forward Voltage	Vsd	Is=2.3A,VGS =0V		0.8	1.2	V
Dynamic						
Total Gate Charge	Qg			16	24	nC
Gate-Source Charge	Qgs	VDS=15V,VGS=10V ID= 2A		3		
Gate-Drain Charge	Qgd	ID- ZA		2.5		
T. O. T.	td(on)			15	20	nS
Turn-On Time	tr	VDD=15V,RL=15Ω		6	12	
Turn-Off Time	td(off)	$I_D=1.0A,V_{GEN}=10V$ $R_G=6\Omega$		10	20	
	tf			40	80	

## TYPICAL CHARACTERISTICS









On-Resistance vs. Drain Current and Gate Voltage

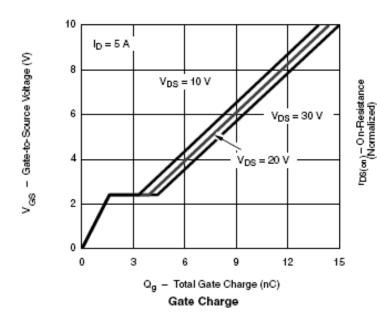
V<sub>DS</sub> - Drain-to-Source Voltage (V)

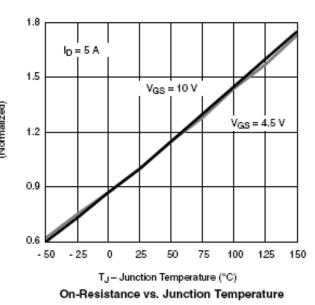
Capacitance

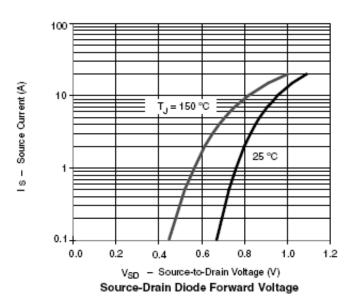
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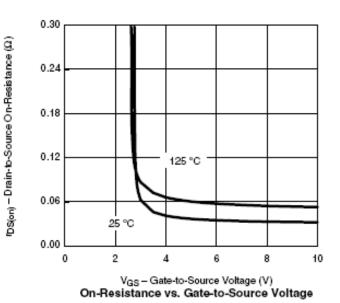
C - Capacitance (pF)

## TYPICAL CHARACTERISTICS

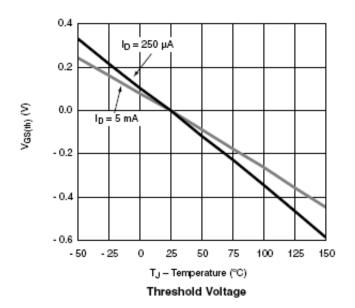


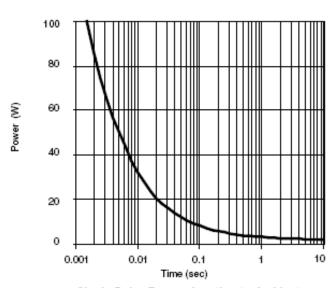




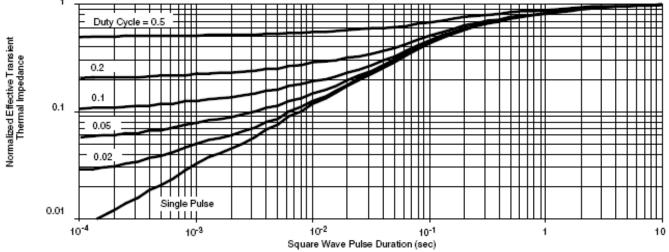


# TYPICAL CHARACTERISTICS





Single Pulse Power, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

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